



PATENT  
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Applicant: Ming-Dou KER et al. Conf.: 9752  
Appl. No.: 09/942,785 Group: 2836  
Filed: August 31, 2001 Examiner: UNASSIGNED  
For: CDM ESD PROTECTION DESIGN USING DEEP N-  
WELL STRUCTURE

*HS*  
*Amendment*  
*2-2102*

PRELIMINARY AMENDMENT

Assistant Commissioner for Patents  
Washington, DC 20231

January 14, 2002

Sir:

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

IN THE SPECIFICATION:

Please replace the paragraph beginning on page 4, line 3, with the following rewritten paragraph:

--In US patent no. 5,901,022, an inductor is added between the input pad and the HBM/MM ESD protection circuit to clamp the CDM ESD stress across the gate oxide of the input buffer.--